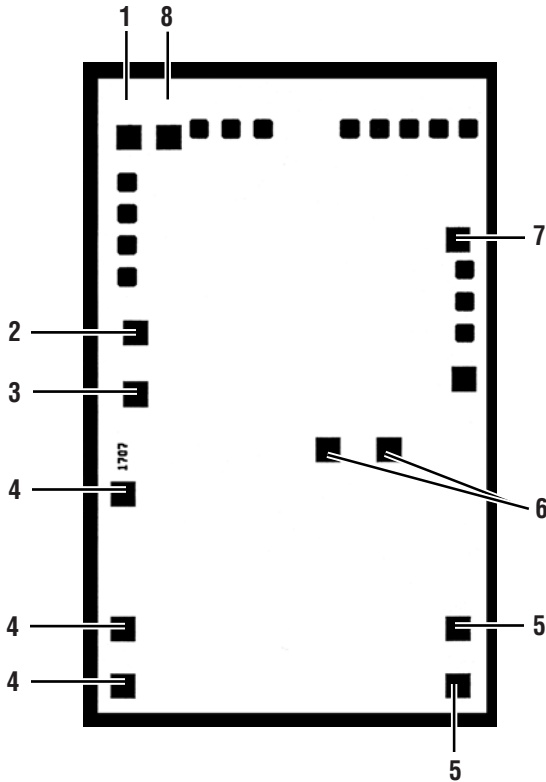


High Efficiency Monolithic
 Synchronous Step-Down Switching Regulator


210 × 116 mils

PAD FUNCTION

1. I_{TH}
2. RUN/SS
3. V_{FB}
4. GND
5. SW
6. V_{IN}
7. SYNC/MODE
8. V_{REF}

DIE CROSS REFERENCE

LTC Finished Part Number	Order DICE CANDIDATE Part Number Below
LTC1707	LTC1707 DICE
LTC1707	LTC1707 DFN

ABSOLUTE MAXIMUM RATINGS

(Note 1)

Input Supply Voltage	-0.3V to 10V
I_{TH} Voltage	-0.3V to 5V
RUN/SS, V_{FB} Voltages	-0.3V to V_{IN}
SYNC/MODE Voltage	-0.3V to V_{IN}
P-Channel Switch Source Current (DC)	800mA
N-Channel Switch Sink Current (DC)	800mA
Peak SW Sink and Source Current	1.5A
Junction Temperature (Note 2)	125°C

DICE/DWF SPECIFICATION

LTC1707

DICE ELECTRICAL TEST LIMITS $V_{IN} = 5V$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNITS
I_{VFB}	Feedback Current	(Note 3)		60	nA
V_{FB}	Regulated Feedback Voltage	(Note 3)	0.78	0.82	V
ΔV_{OVL}	Output Overvoltage Lockout	$\Delta V_{OVL} = V_{OVL} - V_{FB}$	20	110	mV
ΔV_{FB}	Reference Voltage Line Regulation	$V_{IN} = 3V$ to 8.5V (Note 3)		0.01	%/V
$V_{LOADREG}$	Output Voltage Load Regulation	I_{TH} Sinking 2 μ A (Note 3) I_{TH} Sourcing 2 μ A (Note 3)		0.8 -0.8	% %
I_S	Input DC Bias Current Pulse Skipping Mode Burst Mode Operation Shutdown Shutdown	(Note 4) $V_{IN} = 8.5V$, $V_{OUT} = 3.3V$, $V_{SYNC/MODE} = 0V$ $V_{ITH} = 0V$, $V_{IN} = 8.5V$, $V_{SYNC/MODE} = \text{Open}$ $V_{RUN/SS} = 0V$, $3V < V_{IN} < 8.5V$ $V_{RUN/SS} = 0V$, $V_{IN} < 3V$		320 35	μ A μ A μ A μ A
$V_{RUN/SS}$	Run/SS Threshold	$V_{RUN/SS}$ Ramping Positive	0.4	1.0	V
$I_{RUN/SS}$	Soft-Start Current Source	$V_{RUN/SS} = 0V$	1.2	3.3	μ A
$I_{SYNC/MODE}$	SYNC/MODE Pull-Up Current	$V_{SYNC/MODE} = 0V$	0.5	2.5	μ A
f_{OSC}	Oscillator Frequency	$V_{FB} = 0.7V$ $V_{FB} = 0V$	315	385	kHz kHz
V_{UVLO}	Undervoltage Lockout	V_{IN} Ramping Down from 3V (0°C to 70°C) V_{IN} Ramping Up from 0V (0°C to 70°C) V_{IN} Ramping Down from 3V (-40°C to 85°C) V_{IN} Ramping Up from 0V (-40°C to 85°C)	2.55 2.60	2.85 3.00	V V V V
R_{PFET}	$R_{DS(ON)}$ of P-Channel FET	$I_{SW} = -100mA$		0.7	Ω
R_{NFET}	$R_{DS(ON)}$ of N-Channel FET	$I_{SW} = -100mA$		0.8	Ω
I_{PK}	Peak Inductor Current	$V_{IN} = 4V$, $I_{TH} = 1.4V$, Duty Cycle < 40%	0.70	1.10	A
I_{LSW}	SW Leakage	$V_{RUN/SS} = 0V$		± 1000	nA
V_{REF}	Reference Output Voltage	$I_{REF} = 0\mu A$	1.178	1.202	mV
ΔV_{REF}	Reference Output Load Regulation	$0V \leq I_{REF} \leq 100\mu A$		15	mV

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: T_J is calculated from the ambient temperature T_A and power dissipation P_D according to the following formula:

$$T_J = T_A + (P_D \cdot \theta_{JA})$$

Note 3: The LTC1707 is tested in a feedback loop that servos V_{FB} to the balance point for the error amplifier ($V_{ITH} = 0.8V$).

Note 4: Dynamic supply current is higher due to the gate charge being delivered at the switching frequency.